Freeform Search

US Pre-Grant Publication Full-Text Database US Patents Full-Text Database US OCR Full-Text Database EPO Abstracts Database JPO Abstracts Database Derwent World Patents Index IBM Technical Disclosure Bulletins							
Ter	m:	L1 and nitride				区 [记	
Disp	play:	10 Documents	in <u>Display Form</u>	at:	Starting w	ith Number 1	
Generate: C Hit List 6 Hit Count C Side by Side C Image							
		Se	earch Clear	Inter	rupt.		
			Search Hi	story			
DATE:	Sunday	, March 20, 2005	Printable Copy	Create Ca	ase		
Set Name side by side	Query					<u>Hit</u> <u>Count</u>	Set Name result set
DB=Pc	GPB, US	SPT, USOC, EPAB, JI	PAB,DWPI,TDBD	; PLUR=1	ES; OP=OR		
L2	L1 and	nitride				95	<u>L:2</u>

capacitor and ((ALD or (atomic adj layer adj deposition)) with (aluminum adj oxide))

END OF SEARCH HISTORY

<u>L1</u>

<u>L1</u> .

120